DBV (SOT-23-5) PACKAGE

(TOP VIEW)



www.ti.com SLOS647-AUGUST 2009

LOW-POWER SINGLE OPERATIONAL AMPLIFIER

FEATURES

Qualified for Automotive Applications

• Wide Power-Supply Range

- Single Supply: 3 V to 30 V

Dual Supply: ±1.5 V to ±15 V

Large Output Voltage Swing:

0 V to 3.5 V (Min) (V_{CC} = 5 V)

Low Supply Current: 500 μA (Typ)
 Low Input Bias Current: 20 nA (Typ)
 Stable With High Capacitive Loads

DESCRIPTION/ORDERING INFORMATION

The TS321 is a bipolar operational amplifier for cost-sensitive applications in which space savings are important.

ORDERING INFORMATION(1)

T _A	PACK	AGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
-40°C to 125°C	SOT-23-5 – DBV	Reel of 3000	TS321QDBVRQ1	9CNS	

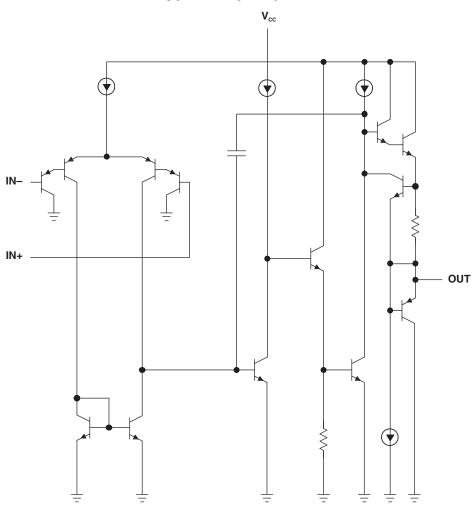
- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



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SCHEMATIC DIAGRAM





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ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
\/	Supply voltage (2)	Single		32	V
V _{CC}	Supply voltage (Dual		±16	V
V_{ID}	Differential input voltage (3)			32	V
VI	Input voltage range (2) (4)		-0.3	32	V
I	Input current ⁽⁴⁾			50	mA
t _{short}	Duration of output short circuit to ground		L	Inlimited	
θ_{JA}	Package thermal impedance, junction to free air (5)(6)	DBV package		206	°C/W
TJ	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

These voltage values are with respect to the midpoint between V_{CC+} and V_{CC-} . Differential voltages are at IN+ with respect to IN-.

(4)

The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V	Cupply valtage	Single supply	3	30	V
V _{CC}	Supply voltage	Dual supply	±1.5	±15	V
T _A	Operating free-air temperature		-40	125	°C

Product Folder Link(s): TS321-Q1

Neither input must ever be more positive than V_{CC+} or more negative than V_{CC-} . Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient (5)temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.



ELECTRICAL CHARACTERISTICS

 $V_{CC+} = 5 \text{ V}, V_{CC-} = \text{GND}, V_{O} = 1.4 \text{ V} \text{ (unless otherwise noted)}$

	PARAMETER	TEST CONDIT	TONS	T _A	MIN	TYP	MAX	UNIT	
M	land offer to the con-	R _S = 0, 5 V < V _{CC+} < 3	0 V.	25°C		0.5	4	>/	
V_{IO}	Input offset voltage	$0 < V_{IC} < (V_{CC+} - 1.5 V_{CC+})$	')	Full range			5	mV	
	Laurent office to account			25°C		2	30	0	
I _{IO}	Input offset current			Full range			50	nA	
	L			25°C		20	150	^	
I _{IB}	Input bias current ⁽¹⁾			Full range			200	nA	
	Large-signal differential voltage	$V_{CC} = 15 \text{ V}, R_L = 2 \text{ k}\Omega$	ı	25°C	50	100		\//\/	
A_{VD}	amplification	$V_0 = 1.4 \text{ V to } 11.4 \text{ V}$		Full range	25			V/mV	
V		V 00 V		25°C	0		V _{CC+} – 1.5	V	
V_{ICR}	Common-mode input voltage (2)	V _{CC} = 30 V		Full range	0		V _{CC+} – 2	V	
-	High-level output voltage		D 01:0	25°C	26	27			
		V 00 V	$R_L = 2 k\Omega$	Full range	25.5				
.,		V _{CC} = 30 V	D 4010	25°C	27	28		V	
V _{OH}			$R_L = 10 \text{ k}\Omega$	Full range	26.5				
		.,,	$R_L = 2 k\Omega$	25°C	3.5				
		$V_{CC} = 5 V$		Full range	3				
.,		D 1010		25°C		5	15	.,	
V_{OL}	Low-level output voltage	$R_L = 10 \text{ k}\Omega$	Full range			20	mV		
GBP	Gain bandwidth product		$V_{CC} = 30 \text{ V}, V_I = 10 \text{ mV}, R_L = 2 \text{ k}\Omega,$ $f = 100 \text{ kHz}, C_I = 100 \text{ pF}$			0.8		MHz	
SR	Slew rate	$V_{CC} = 15 \text{ V}, V_I = 0.5 \text{ V}$ $R_L = 2 \text{ k}\Omega, C_L = 100 \text{ pf}$		25°C		0.4		V/µs	
φ _m	Phase margin			25°C		60		0	
CMRR	Common-mode rejection ratio	R _S ≤ 10 kΩ		25°C	65	85		dB	
I _{SOURCE}	Output source current	$V_{CC} = 15 \text{ V}, V_{O} = 2 \text{ V},$	V _{ID} = 1 V	25°C	20	40		mA	
1	Output sink surrent	V _{CC} = 15 V, V _{ID} = 1 V	V _O = 2 V	25°C	10	20		mA	
ISINK	Output sink current	$v_{CC} = 15 \text{ V}, v_{ID} = 1 \text{ V}$	V _O = 0.2 V	25°C	12	50		μΑ	
I _O	Short-circuit to GND	V _{CC} = 15 V		25°C		40	60	mA	
SVR	Supply-voltage rejection ratio	V _{CC} = 5 V to 30 V		25°C	65	110		dB	
			$V_{CC} = 5 V$	0500		500	800		
	Tatal averally average	No local	V _{CC} = 30 V	25°C		600	900	^	
I _{CC}	Total supply current	No load	V _{CC} = 5 V	Full ronge		600	900	μΑ	
		$V_{CC} = 30 \text{ V}$		Full range	 		1000		
THD	Total harmonic distortion	$V_{CC} = 30 \text{ V}, V_{O} = 2 \text{ V}_{pp}$ $R_{L} = 2 \text{ k}\Omega, f = 1 \text{ kHz}, C$, A _V = 20 dB, C _L = 100 pF	25°C		0.015		%	
e _N	Equivalent input noise voltage	$V_{CC} = 30 \text{ V}, f = 1 \text{ kHz},$	R _S = 100 Ω	25°C		50		nV/√ Hz	

⁽¹⁾ The direction of the input current is out of the device. This current essentially is constant, independent of the state of the output, so no loading change exists on the input lines.

⁽²⁾ The input common-mode voltage of either input signal should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V_{CC+} – 1.5 V, but either or both inputs can go to 32 V without damage.



PACKAGE OPTION ADDENDUM



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
TS321QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	9CNS	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TS321-Q1:



PACKAGE OPTION ADDENDUM

10-Dec-2020

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Aug-2017

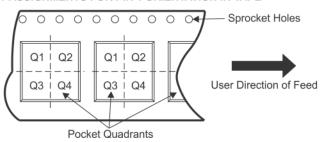
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS321QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3

www.ti.com 3-Aug-2017

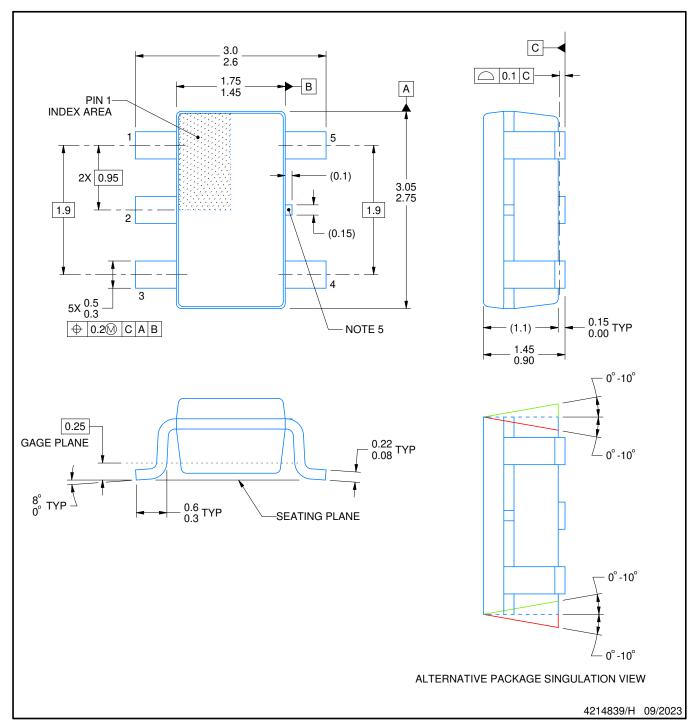


*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TS321QDBVRQ1	SOT-23	DBV	5	3000	202.0	201.0	28.0	



SMALL OUTLINE TRANSISTOR



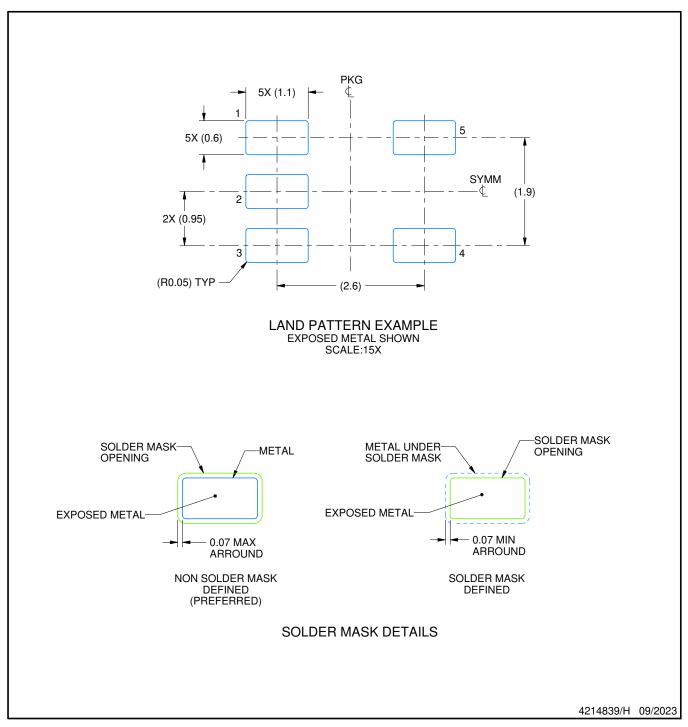
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR

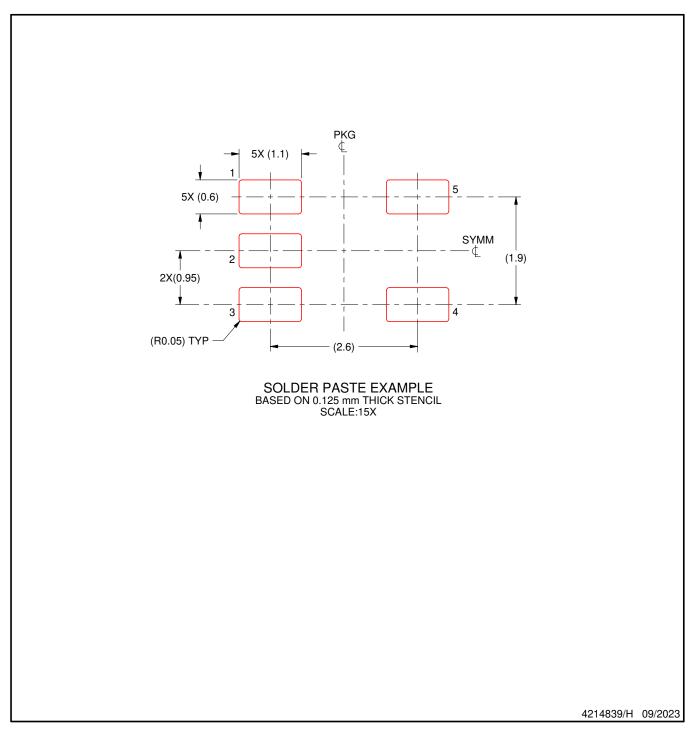


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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